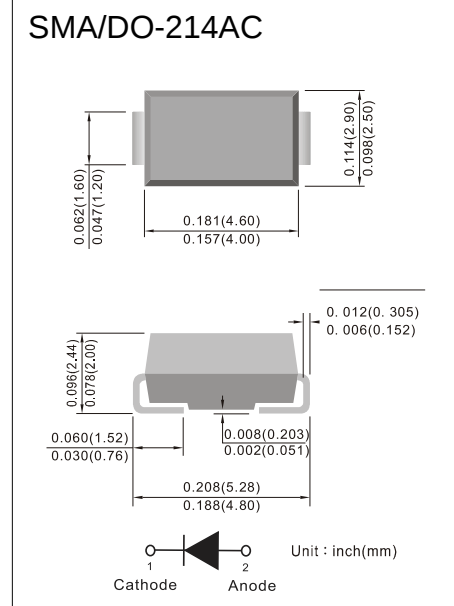


■ Features

- Glass passivated junction chip
- Ideal for automated placement
- Super fast recovery time for high efficiency
- Built-in strain relief
- Comply with RoHS standard, halogen-free

■ Mechanical Data

- package:SMA/DO-214AC
- Polarity: Indicated by cathode band
- Epoxy: UL 94V-0 rate flame retardant
- Mounting Position : Any



■ Maximum Ratings And Electrical Characteristics($T_A=25^{\circ}\text{C}$ unless otherwise noted)

PARAMETER	SYMBOL	ES1A	ES1B	ES1C	ES1D	ES1F	ES1G	ES1H	ES1J	UNIT
Maximum repetitive peak reverse voltage	VRRM	50	100	150	200	300	400	500	600	V
Maximum RMS voltage	VRMS	35	70	105	140	210	280	350	420	V
Maximum DC blocking voltage	VDC	50	100	150	200	300	400	500	600	V
Maximum average forward rectified current	IF(AV)	1								A
Peak forward surge current, 8.3 ms single half sine-wave superimposed on rated load	IFSM	30								A
Maximum instantaneous forward voltage (Note 1) @ 1 A	VF	0.95				1.3		1.7		V
Maximum reverse current @ rated VR TJ=25°C TJ=125°C	IR	5 100								µA
Maximum reverse recovery time (Note 2)	trr	35								ns
Typical junction capacitance (Note 3)	CJ	16				18				pF
Typical thermal resistance	RθJL RθJA	35 85								°C/W
Operating junction temperature range	TJ	- 55 to +150								°C
Storage temperature range	TSTG	- 55 to +150								°C

Note 1: Pulse test with $PW=300\mu\text{s}$, 1% duty cycle

Note 2: Reverse Recovery Test Conditions: $I_F=0.5\text{A}$, $I_R=1.0\text{A}$, $I_{RR}=0.25\text{A}$

Note 3: Measured at 1 MHz and Applied $V_R=4.0$ Volts



■ Ratings And Characteristics Curves($T_A=25^{\circ}\text{C}$ unless otherwise noted)

FIG.1 MAXIMUM FORWARD CURRENT DERATING CURVE

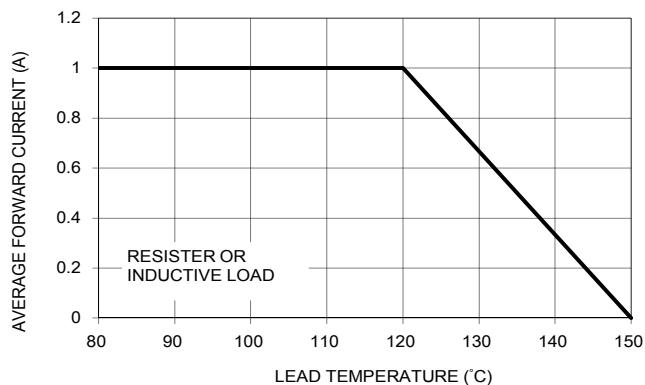


FIG. 2 TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

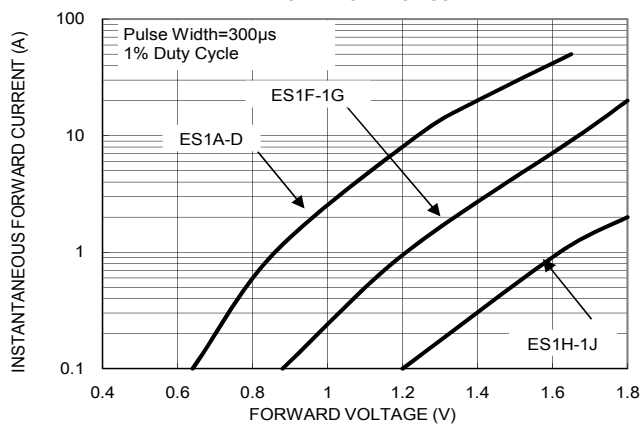


FIG. 3 MAXIMUM NON-REPETITIVE FORWARD PEAK SURGE CURRENT

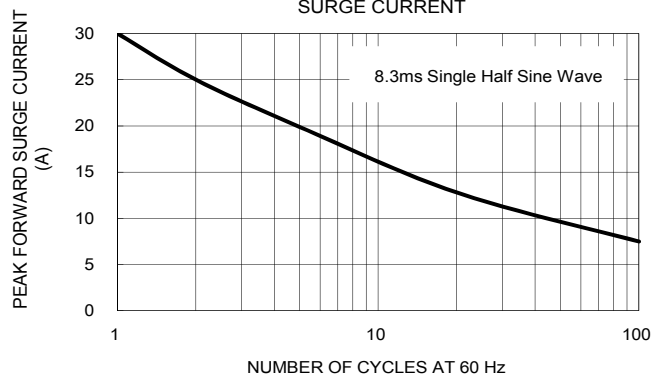


FIG. 4 TYPICAL REVERSE CHARACTERISTICS

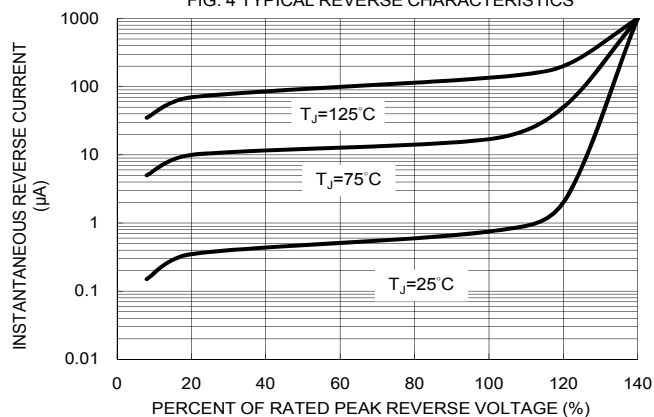


FIG. 5 TYPICAL JUNCTION CAPACITANCE

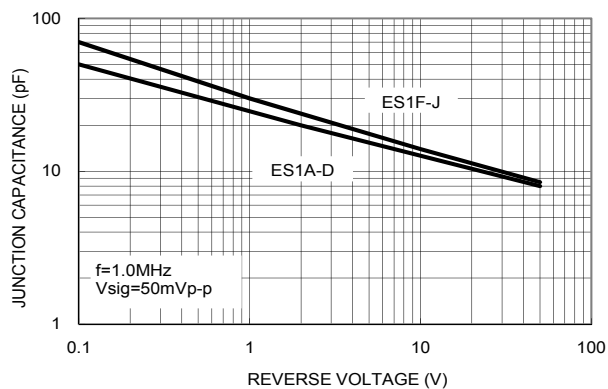


FIG.6- REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM

